

**FABRICATION OF FREQUENCY SELECTIVE STRUCTURE AND  
EVALUATION OF MICROWAVE TRANSMISSION ON ENERGY  
SAVING GLASS**

LIM HUEY SIA

A thesis submitted in  
fulfilment of the requirements for the award of the  
Degree of Master of Electrical Engineering with Honors

Faculty of Electrical and Electronic Engineering  
Universiti Tun Hussein Onn Malaysia

FEB 2015

To my beloved late father (*Lim Seng Ong*),  
mother (*Gan Mui Eng*), brothers  
and sisters



PTTA UTHM  
PERPUSTAKAAN TUNKU TUN AMINAH

## ACKNOWLEDGEMENT

First I would like to thank my project supervisor, Associate Professor Dr. Nafarizal Bin Nayan and co-supervisor, Dr. Samsul Haimi Bin Dahlan and Dr. Ghafffer I. Kiani who had presently giving me guidance throughout the entire project. Under their supervision, many aspects regarding this project had been explored and with the knowledge, idea and support receive from them, this thesis can be presented in the time given. Besides, I would also like to extend my sincerest special thanks and appreciation to all the lecturer and researcher in Microelectronics and Nanotechnology – Shamsuddin Research Centre (MiNT – SRC), University Tun Hussien Onn Malaysia (UTHM) for their generous support and help in completing this study. And also thanks to Puan Faedahana Binti Mokhter and En. Ahmad Nasrull Bin Mohamed, technician in the MiNT-SRC research center that helps in carry out my master project.

Secondly I would like to show my appreciation to University Tun Hussien Onn Malaysia (UTHM) Microelectronics and Nanotechnology – Shamsuddin Research Centre (MiNT – SRC) for providing me with the facilities to carry out my project. Not forgetting, the Malaysian Technical University Network (MTUN) Centre of Excellence (COE) vot number C024 and Short Term Grant of University Tun Hussien Onn Malaysia that provide the financial support throughout the years. I wish to also express my gratitude to UTHM Postgraduate Incentive Research Grant for the financial support.

Thirdly I would like to thanks to Advanced Printed Circuit Board Design Laboratory for the equipment and facilities used throughout the research carried out. And thanks to the En. Mahmud Bin Munajat, technician of the lab that helps me in the experiment carried out. Besides that, I would like to express my thanks to Research Centre for Applied Electromagnetics (EM Center) for the testing facility used in my project. In here, I would like to thanks to Pn. Miskiah Binti Muhammad

Ihsan, En Mohd Rostam Bin Annuar and En. Sharifunazri Bin Johadi which had helped me in carried out the experiment in my project.

Last but not least, special thanks to all of my family members and friends who has given me support throughout my academic years. Also all people who in one way or another contributed ideas and sharing tools, parts and components to ensure the success of this project. Thank you.



## ABSTRACT

The use of energy saving glass has become very popular in the modern day building design. This energy saving property is achieved by applying a very thin tin oxide ( $\text{SnO}_2$ ) coating on one side of the glass. This coating can provide good thermal insulation to the buildings by blocking infrared rays while being transparent to visible part of the spectrum. Drawbacks of these energy saving windows is that it also attenuates the transmission of useful microwave signals through them. These signals fall within the frequency band of 0.8GHz to 2.2GHz. In order to pass these signals through the coated glass, the use of aperture type frequency selective surface (FSS) has being proposed. In the present work,  $\text{SnO}_2$  thin film with FSS structure was fabricated using RF magnetron sputtering technique and printed circuit board technology. Deposition time, dissipation power and oxygen flow rate were varied during the sputtering deposition process. Atomic force microscopy (AFM) and field emission-scanning electron microscopy (FE-SEM) were used to analyze the surface morphology and roughness of the  $\text{SnO}_2$  thin film. Two point electrical probe analysis was used to determine the sheet resistance and resistivity of the  $\text{SnO}_2$  thin film. Thickness of  $\text{SnO}_2$  thin film was measured using surface profiler. Good correlation between the surface properties and electrical properties of  $\text{SnO}_2$  thin film was obtained. Microwave transmission through  $\text{SnO}_2$  coated glass with FSS structure was also analyzed using network analyzer. The result of computer simulation was confirmed and consistent with the network analyzer results that showed the improvement of  $\text{SnO}_2$  coated glass with the FSS structure. Thermal analysis demonstrated that FSS structure had allows the transmission of GSM mobile signal penetrate in the buildings while blocking the infrared light with the  $\text{SnO}_2$  film properties.

## ABSTRAK

Penggunaan kaca yang boleh menjimatkan tenaga adalah sangat popular dalam bangunan moden masa kini. Konsep kaca penjimatan tenaga boleh dihasilkan dengan menggunakan timah oksida ( $\text{SnO}_2$ ) yang sangat nipis dan disalut pada satu permukaan kaca. Lapisan ini akan menebat haba dengan baik pada bangunan-bangunan, iaitu dengan menghalang sinaran inframerah daripada telus ke dalam bangunan. Salah satu kelemahan salutan  $\text{SnO}_2$  ini adalah ia akan melemahkan penghantaran isyarat yang berguna seperti gelombang telefon daripada melalui salutan  $\text{SnO}_2$ . Penggunaan struktur frekuensi terpilih (FSS) adalah dicadangkan untuk mengatasi masalah ini. Di dalam projek ini, lapisan  $\text{SnO}_2$  dan struktur FSS dibentuk dengan menggunakan RF *magnetron sputtering* dan teknologi papan litar tercetak. Mikroskop tekanan atom (AFM) dan mikroskop imbasan elektron – pancaran medan (FE-SEM) telah digunakan untuk menganalisis morfologi permukaan dan kekasaran filem nipis  $\text{SnO}_2$ . *Two point probe* digunakan untuk menentukan rintangan filem nipis  $\text{SnO}_2$ . Ketebalan filem nipis diukur menggunakan *surface profiler*. Perkaitan yang baik di antara sifat-sifat permukaan dan sifat elektrik  $\text{SnO}_2$  filem nipis telah ditemui. Ketebalan filem ini juga sangat berhubung kait dengan sifat-sifat elektrik filem. Kadar penembusan gelombang mikro melalui salutan  $\text{SnO}_2$  berserta struktur FSS dikaji menggunakan *network analyzer*. Hasil simulasi komputer telah disahkan dan konsisten dengan hasil kajian *network analyzer* yang menunjukkan peningkatan dalam penembusan gelombang melalui kaca bersalut  $\text{SnO}_2$  dengan struktur FSS. Hasil kajian suhu juga mendapati struktur FSS telah meningkatkan penghantaran isyarat GSM dengan menembusi dalam bangunan manakala menyekat pemanasan inframerah.

## CONTENTS

	<b>TITLE</b>	<b>i</b>
	<b>DECLARATION</b>	<b>ii</b>
	<b>DEDICATION</b>	<b>iii</b>
	<b>ACKNOWLEDGEMENT</b>	<b>iv</b>
	<b>ABSTRACT</b>	<b>vi</b>
	<b>CONTENTS</b>	<b>viii</b>
	<b>LIST OF FIGURES</b>	<b>xii</b>
	<b>LIST OF SYMBOLS AND ABBREVIATIONS</b>	<b>xix</b>
<b>CHAPTER 1</b>	<b>INTRODUCTION</b>	<b>1</b>
	1.1 Background of Research	1
	1.2 Problem Statement and Objective	3
	1.3 Scope of Research	3
	1.4 Outline of Thesis	4
<b>CHAPTER 2</b>	<b>LITERATURE REVIEW</b>	<b>5</b>
	2.1 Energy Saving Glass	6
	2.2 Thin Film Deposition	9
<b>CHAPTER 3</b>	<b>RESEARCH METHODOLOGY</b>	<b>11</b>
	3.1 Radio Frequency (RF) Magnetron Sputtering Deposition	12
	3.2 Computer Simulation Technology (CST)	15
	3.2.1 Electromagnetic Simulation Workflow	16
	3.3 Printed Circuit Board Technology and Fabrication of FSS Structure	17
	3.4 Thin Film Characterization	19
	3.4.1 Surface Profiler and Two Point Probe	

3.4.2	Field Emission Scanning Electron Microscope (FESEM) and Atomic Force Microscope (AFM)	21
3.4.3	X-Ray Diffraction (XRD) and UV-Vis	23
3.5	Spectrum Analyzer, Network Analyzer, Glass and Thermal Properties	25
3.6	Glass Dielectric Constant Measurement	30
<b>CHAPTER 4 ELECTROMAGNETIC SIMULATION USING CST: FSS STRUCTURE</b>		<b>31</b>
4.1	CST Simulation Using Various SnO <sub>2</sub> Sheet Resistance Values	32
4.1.1	CST Simulation Using Conventional Sheet Resistance	34
4.1.2	CST Simulation Using Sheet Resistance of SnO <sub>2</sub> Thin Film Deposited Using RF Magnetron Sputtering System	36
4.2	CST Simulation Using Various Shape of FSS Structure	38
<b>CHAPTER 5 SnO<sub>2</sub> THIN FILM ANALYSIS</b>		<b>45</b>
5.1	Electrical Properties of SnO <sub>2</sub> Thin Film Deposited at Various Parameters	45
5.1.1	Thickness and Sheet Resistance of SnO <sub>2</sub> Deposited at Different Deposition Time	46
5.1.2	Correlation between Thickness and Sheet Resistance of SnO <sub>2</sub> Thin Film	48
5.2	Physical properties of SnO <sub>2</sub> Thin Film	48
5.2.1	Roughness analysis using AFM	49
5.2.2	FESEM Result of SnO <sub>2</sub> Thin Film	50
5.3	Structural Composition and Optical Properties of SnO <sub>2</sub> Thin Film	51
5.3.1	XRD Result of SnO <sub>2</sub> Thin Film	51
5.3.2	Optical Transmission through SnO <sub>2</sub> Thin	52



	Film	
5.4	Thickness and Sheet Resistance of SnO <sub>2</sub> Deposited at Different Oxygen Flow Rate	53
5.5	Physical properties of AFM Result for SnO <sub>2</sub> thin film	55
5.5.1	FESEM Result of SnO <sub>2</sub> Thin Film	56
5.5.2	XRD Result of SnO <sub>2</sub> Thin Film Deposited at Different Oxygen Flow Rate	57
5.6	Thickness and Sheet Resistance of SnO <sub>2</sub> Deposited at Different Dissipation Power	59
5.6.1	AFM Result of SnO <sub>2</sub> Thin Film Deposited at Different Dissipation Power	61
5.6.2	FESEM Result of SnO <sub>2</sub> Thin Film Deposited at Different Dissipation Power	62
5.7	XRD Result of SnO <sub>2</sub> Thin Film Deposited at Different Dissipation Power	64
<b>CHAPTER 6</b>	<b>MOBILE RADIO SIGNAL TRANSMISSION AND THERMAL PROPERTIES THROUGH SnO<sub>2</sub> THIN FILM DEPOSITED AT VARIOUS PARAMETERS</b>	<b>66</b>
6.1	Signal Magnitude Analysis	67
6.1.1	Signal Magnitude Analysis Result of SnO <sub>2</sub> Film Deposited at Different Deposition Time	68
6.1.2	Signal Magnitude Analysis Result of SnO <sub>2</sub> Film Deposited at Different Oxygen Flow Rate	72
6.1.3	Signal Magnitude Analysis Result of SnO <sub>2</sub> Film Deposited at Different Dissipation Power	77
6.2	Signal Transmission Analysis	82
6.2.1	Signal Transmission Result of SnO <sub>2</sub> Film Deposited At Different Deposition Time	82

6.2.2	Signal Transmission Result of SnO <sub>2</sub> Film Deposited At Different Oxygen Flow Rate	84
6.2.3	Signal Transmission Result of SnO <sub>2</sub> Film Deposited At Different Dissipation Power	85
6.3	Thermal Insulation Properties	87
<b>CHAPTER 7</b>	<b>CONCLUSION</b>	<b>88</b>
7.1	Strength of this Project	90
7.2	Future Work	90
	<b>REFERENCES</b>	<b>92</b>
	<b>APPENDICES</b>	<b>102</b>



**PTTA UTHM**  
PERPUSTAKAAN TUNKU TUN AMINAH

## LIST OF FIGURES

2.1	Illustration of energy saving glass with the FSS structure.	8
3.1	Flow chart to fabricate energy saving glass	11
3.2	Tin oxide (SnO <sub>2</sub> ) target material.	12
3.3	Fluorine Tin Oxide (FTO) target material.	12
3.4	Schematic diagram of magnetron source.	13
3.5	Magnetron sputtering operation system.	14
3.6	Overview of RF magnetron sputtering setup.	15
3.7	CST studio suite 2013 used for simulation.	15
3.8	Basics procedure in CST simulation.	16
3.9	Process flow of FSS formation.	17
3.10	Procedure on frequency selective structure (FSS) printed on the glass.	18
3.11	Front illustration for the glass before and after coating.	19
3.12	Surface profiler Alpha Step IQ.	20
3.13	Electrical properties measured using 2 point probing.	21
3.14	Image of the FESEM (JEOL JSM-7600F) operation system.	21
3.15	Configuration of the FESEM (JEOL JSM-7600F) operation system.	22
3.16	Image of the Park System AFM (model XE-100) operation system.	22
3.17	Configuration of the Park System AFM (model	23

	XE-100) and its operation.	
3.18	Glazing incidence diffraction experimental setup.	24
3.19	Picture of the Panalytical X'Pert Pro-MRD used for the measurement.	25
3.20	Illustration of UV-Vis spectrometry.	25
3.21	Measurement setup for spectrum analyzer.	25
3.22	Spectrum analyzer of Advantest R3132 used in measurement.	26
3.23	Experimental setup for spectrum analysis.	26
3.24	Measurement setup for network analyzer testing.	27
3.25	Picture of Rohde&Schwarz network analyzer (ZVB 4) used in the measurement.	27
3.26	Experimental setup for the network analyzer testing.	28
3.27	Measurement setup for temperature measurement.	28
3.28	Experimental setup for temperature measurement.	29
3.29	IR thermometer used in temperature measurement.	29
3.30	Agilent 4291B used for dielectric constant measurement.	30
3.31	Glass attached to the rod for measurement.	30
4.1	Dielectric constant measured by Agilent 4291B.	31
4.2	Illustration of sheet resistance measured by the 2 point probe.	32
4.3	Microwave transmission at various ohmic sheet resistances and without FSS structure.	32
4.4	Microwave transmission at various ohmic sheet resistances and with FSS structure.	33
4.5	Microwave transmission at 4 ohmic sheet resistances and with and without FSS structure.	34
4.6	Microwave transmission at 6 ohmic sheet resistances and with and without FSS structure.	35

4.7	Microwave transmission at various deposition times with the FSS structure.	36
4.8	Microwave transmission at various oxygen flow rate with the FSS structure.	37
4.9	Microwave transmission at various dissipation powers with the FSS structure.	37
4.10	Design of cross-dipole frequency selective surface unit cell on energy saving glass.	39
4.11	Design of circle frequency surface unit cell on energy saving glass.	39
4.12	Design of pentagon frequency selective surface unit cell on energy saving glass.	39
4.13	Design of triangle frequency selective surface unit cell on energy saving glass.	40
4.14	Design of combine structure frequency selective surface unit cell on energy saving glass.	40
4.15	A plot demonstrating technique to measure full width half maximum, minimum transmission loss and peak frequency from the simulation result.	41
4.16	Transmission loss through different shapes of frequency selective surface.	42
4.17	Effect on different shapes through FWHM and peak frequency analysis.	42
4.18	Minimum transmission loss through different shapes of frequency selective structure.	43
4.19	Surface area etched with the minimum transmission loss with different shapes.	44
5.1	Thickness of SnO <sub>2</sub> film under different deposition time.	46
5.2	Correlation between sheet resistance and resistivity of the SnO <sub>2</sub> thin film under different deposition time.	47

5.3	AFM image of SnO <sub>2</sub> thin film deposited at (a) 10 minutes, (b) 20 minutes and (c) 30 minutes deposition time.	49
5.4	FESEM image of SnO <sub>2</sub> thin film deposited at (a) 10minutes, (b) 20minutes and (c) 30minutes.	50
5.5	XRD image of SnO <sub>2</sub> thin film that deposited at different deposition time.	51
5.6	Transmittance of SnO <sub>2</sub> thin film that deposited at different deposition time.	52
5.7	Thickness and deposition rate of SnO <sub>2</sub> film under different oxygen flow rate.	53
5.8	Correlation between sheet resistance and resistivity under different oxygen flow rate.	54
5.9	AFM image of SnO <sub>2</sub> thin film deposited at (a) 0 sccm, (b) 4sccm, (c) 8sccm and 16sccm.	55
5.10	FESEM images of SnO <sub>2</sub> thin film deposited at (a) 0sccm, (b) 4sccm, (c) 8sccm and (d) 16sccm of O <sub>2</sub> flow rate. The RF power and total pressure were 225W and 8.25mTorr, respectively.	56
5.11	XRD image of SnO <sub>2</sub> thin film that deposited at different oxygen flow rate.	58
5.12	Transmittance of the SnO <sub>2</sub> thin film that deposited at different oxygen flow rate.	58
5.13	Correlation of thickness and deposition rate of SnO <sub>2</sub> thin film with different dissipation power.	59
5.14	Correlation between sheet resistance and resistivity under different dissipation power.	60
5.15	AFM image of SnO <sub>2</sub> thin film that deposited (a) 150W, (b) 200W, (c) 225W, (d) 250W and (e) 300W.	62
5.16	FESEM images of SnO <sub>2</sub> thin film deposited at (a) 150W, (b) 200W, (c) 225W and (d) 250W and (e)	63

300W of dissipation power. The deposition time and total pressure were 20minutes and 8.25mTorr, respectively.

5.17	XRD image of SnO <sub>2</sub> thin film that deposited at different dissipation power.	64
5.18	Transmittance of SnO <sub>2</sub> thin film that deposited at different dissipation power.	65
6.1	Mobile signal strength tested with spectrum analyzer at (a) 0°, (b) 15° (c) 30°.	67
6.2	Signal magnitude analysis on a SnO <sub>2</sub> thin film with FSS structure that deposited at different deposition time	68
6.3	Signal magnitude analysis on a SnO <sub>2</sub> thin film with FSS structure that deposited at different deposition time.	69
6.4	Signal magnitude analysis at 15 degree on a SnO <sub>2</sub> thin film that deposited at different deposition time.	70
6.5	Signal magnitude analysis at 15 degree on a SnO <sub>2</sub> thin film with FSS structure that deposited at different deposition time.	70
6.6	Signal magnitude analysis at 30 degree on a SnO <sub>2</sub> thin film that deposited at different deposition time.	71
6.7	Signal magnitude analysis at 30 degree on a SnO <sub>2</sub> thin film with FSS structure that deposited at different deposition time.	72
6.8	Signal magnitude analysis on a SnO <sub>2</sub> thin film that deposited at different oxygen flow rate.	73
6.9	Signal magnitude analysis on a SnO <sub>2</sub> thin film with FSS structure that deposited at different oxygen flow rate.	73

6.10	Signal magnitude analysis at 15 degree on a SnO <sub>2</sub> thin film that deposited at different oxygen flow rate.	74
6.11	Signal magnitude analysis at 15 degree on a SnO <sub>2</sub> thin film with FSS structure that deposited at different oxygen flow rate.	75
6.12	Signal magnitude analysis at 30 degree on a SnO <sub>2</sub> thin film that deposited at different oxygen flow rate.	76
6.13	Signal magnitude analysis at 30 degree on a SnO <sub>2</sub> thin film with FSS structure that deposited at different oxygen flow rate.	76
6.14	Signal magnitude analysis on a SnO <sub>2</sub> thin film that deposited at different dissipation power.	77
6.15	Signal magnitude analysis on a SnO <sub>2</sub> thin film with the FSS structure that deposited at different dissipation power.	78
6.16	Signal magnitude analysis at 15 degree on a SnO <sub>2</sub> thin film that deposited at different dissipation power.	79
6.17	Signal magnitude analysis at 15 degree on a SnO <sub>2</sub> thin film with the FSS structure that deposited at different dissipation power.	79
6.18	Signal magnitude analysis at 30 degree on a SnO <sub>2</sub> thin film that deposited at different dissipation power.	80
6.19	Signal magnitude analysis at 30 degree on a SnO <sub>2</sub> thin film with the FSS structure that deposited at different dissipation power.	81
6.20	Signal transmission testing on a SnO <sub>2</sub> thin film that deposited at different deposition time.	82
6.21	Signal transmission testing on a SnO <sub>2</sub> thin film	83



	with the FSS structure that deposited at different deposition time.	
6.22	Signal transmission testing on a SnO <sub>2</sub> thin film that deposited at different oxygen flow rate.	84
6.23	Signal transmission testing on a SnO <sub>2</sub> thin film with the FSS structure that deposited at different oxygen flow rate.	85
6.24	Signal transmission testing on a SnO <sub>2</sub> thin film that deposited at different dissipation power.	86
6.25	Signal transmission testing on a SnO <sub>2</sub> thin film with the FSS structure that deposited at different dissipation power.	86
6.26	Measured temperature for different samples of glass.	87



### LIST OF SYMBOLS AND ABBREVIATIONS

d	-	Distance
$\Theta$	-	Bragg angle
$\lambda$	-	Wavelength
l	-	Length
A	-	Area
w	-	Width
R	-	Resistance
Rho	-	Resistivity
R <sub>s</sub>	-	Sheet Resistance
t	-	Thickness
SnO <sub>2</sub>	-	Tin dioxides
FTO	-	Fluorine Tin Oxide
FSS	-	Frequency Selective Structure
AFM	-	Atomic Force Microscope
FE-SEM	-	Field Emission Scanning Electron Microscope
Na <sub>2</sub> CO <sub>3</sub>	-	Sodium Carbonate
NaOH	-	Sodium Hydroxide
XRD	-	X-Ray Diffraction
CST	-	Computer Simulation Technology
RF	-	Radio Frequency
CVD	-	Chemical Vapor Deposition
O <sub>2</sub>	-	Oxygen
Ar	-	Argon
DC	-	Direct Current
RF	-	Radio Frequency
Cu	-	Copper

PSPD	-	Position-Sensitive Photo Detector
Au	-	Gold
2D	-	Two Dimensional
3D	-	Three Dimensional



## CHAPTER 1

### INTRODUCTION

#### 1.1 Background of Research

Malaysia is a tropical country with hot and wet weather all along the years [1]. With the weather of 34°C in average, air conditioning is basic equipment in modern buildings to release the heats to outside [2]. Thus, electrical power consumption increases with the air conditioning usage in the buildings. In addition, heavy usage of air conditioning is not good for the mother earth due to depleting of ozone layer [2]. Recently, energy saving glass has been developed to overcome this problem [3–12]. Energy saving glass could help to reduce the temperature inside the buildings by reflecting the infrared light that penetrates through the building.

The most basic energy saving glass is a glass that applied with a very thin tin oxide ( $\text{SnO}_2$ ) film on it. This  $\text{SnO}_2$  material is a semiconducting oxide that have higher band gap that are suitable in the gas sensors [13–17] due to the higher free electrons in the oxygen vacant holes and thus increased the electrical conductivity of the thin film, solar cells [18], flat panels display [19] and photo catalysis [20]. However, the disadvantage of the energy saving glass is that it reflects the important electromagnetic wave such as GSM mobile signal, GPS and Bluetooth. In order to improve the electromagnetic signal inside the building, FSS had been added into the energy saving glass [6], [8], [21–24]. This FSS structure helps to enhance the electromagnetic wave inside the building. Different FSS structure will give different transmission at various frequencies. The optimized FSS structure will give the better transmission in the particular frequency.

FSS is a structure that allow the certain frequencies to passed through it while block other frequencies. The used of FSS in this project was to improve the microwave frequencies. In the past few years, many researchers had tried to apply different structure on the energy saving glass [6], [21–25]. Bandpass FSS that act as filter with single, double and triple glass used to improve the transmission of RF/microwave frequencies. The sheet resistance of the film plays a vital role in the improvement of the energy saving glass with the FSS structure. From Liu *et al* findings, decreased in sheet resistance will increase the shielding effect of the electromagnetics wave [26]. The material of the metal oxide had the effects towards the sheet resistance of the film. The transmission of the electromagnetic wave affects once the sheet resistance changed.

Besides that, most of the researchers were using the Pilkington energy saving glass to form the FSS structure on it with the laser technique [27]. In this thesis, fabrication of energy saving glass with FSS structure will be presented. The fundamental properties of coated SnO<sub>2</sub> thin film and its testing toward FSS applications will be discussed. These testing and analyses are needed for optimum usage of energy saving glass application at the modern design building.

Fluorine doped tin oxide (FTO) is the common material used for the energy saving glass that fabricated by Pilkington United Kingdom (UK) [28]. The technique used by Pilkington was chemical vapor deposition (CVD) technique. However, FTO material is not an environmental friendly material due to fluorine gas process which is a toxic gas. Thin film fabrication under CVD technique will require high temperature which needs more time in production.

Indium tin oxide (ITO) also been found in the microwave frequency application [29]. But, the ITO is an expensive material that will results in high production cost. In the present research, magnetron sputtering process will be used to fabricate SnO<sub>2</sub> thin film. The deposition was done in room temperature which had reduced the processing time and then lead to cost saving effect. Besides that, the energy saving glass available for four season country is double panels that argon gas was filled in the middle of it [6], [9], [12], [21], [28], [30] and currently none of the research was reported in Malaysia. This energy saving glass is specially designed for four season countries. While Malaysia is a tropical country that only needs a single panel of energy saving glass [31]. For single panel energy saving glass is relatively

cheaper than the double panel energy saving glass that filled with Argon gas.  $\text{SnO}_2$  was used as the material for energy saving glass due to its high reflectivity towards the infrared light (IR) [32–34]. Besides that,  $\text{SnO}_2$  thin film is also chemically stable that can stay long lasting [35–37].

## 1.2 Problem Statement and Objective

Nowadays, energy saving glass can keep the room cold at the summer and warm at the winter. But at the same time it attenuates the useful microwave frequencies such as GSM mobile signal. Because of this, a FSS structure needs to be added into energy saving glass to improve the transmission of the energy saving glass. Different design of FSS can have different of transmission on the glass. The transmission loss also been influenced by the sheet resistance of the film.

The objectives of this project are to:

1. To simulate the transmission of the microwave signal through energy saving glass with different structure of FSS.
2. To experimentally deposit tin oxide ( $\text{SnO}_2$ ) on glass substrate using RF magnetron sputtering technique and evaluate its characteristics.
3. To evaluate the heat reduction, mobile radio signal transmission through the  $\text{SnO}_2$  glass with FSS structure and without FSS structure fabricated by RF magnetron sputtering.

## 1.3 Scope of Research

In order to meet above objectives, this project is carried out according to below:

1. Computer simulation using CST software for different FSS structure in microwave frequencies.
2. Fabrication of FSS structure using printed circuit board technology.
3. Deposition of  $\text{SnO}_2$  thin film using RF magnetron sputtering plasma.
4. Surface morphology, optical and electrical properties of  $\text{SnO}_2$  thin film analyses.
5. Microwave transmission analysis in the frequency range of 0.8-2.2GHz through  $\text{SnO}_2$  coated glass with FSS structures.

#### 1.4 Outline of Thesis

This thesis is consists of 7 chapters. The first chapter describes an overview of this project. The second chapter explains the literature review of previous works and techniques used in this project. The third chapter presents the experimental setup and equipment used for analyses. The fourth chapter explains the SnO<sub>2</sub> thin film analysis on electrical, physical and optical properties. The fifth chapter describes the CST simulation with different FSS structures and sheet resistance obtains from the electrical properties of the SnO<sub>2</sub> film. The sixth chapter presents the microwave transmission analysis tested with spectrum and network analyzers. Finally, the last chapter described conclusion of the findings throughout the project and propose future work.



PTTA UTHM  
PERPUSTAKAAN TUNKU TUN AMINAH

## CHAPTER 2

### LITERATURE REVIEW

Energy saving glass was widely applied in the buildings nowadays. This energy saving glass used to save the power consumption and the mother earth [38]. Malaysia is a tropical country which is hot and wet weather, throughout the year. Energy saving glass was applied a transparent metallic oxide layer on it. The metal oxide has the ability to reflect the electromagnetic radiation from penetrates into the buildings. But this metallic oxide layer also attenuates the useful signal such as GSM mobile radio signal. In order to improve the electromagnetic wave such as GSM mobile radio signal, a FSS was introduced. The main reason of applying FSS glass was to eliminate the electromagnetic radiation of infrared as much as possible and then the electromagnetic wave of GSM mobile radio signal can be passing through.

Energy saving glass had been widely explored by many researchers to obtain better transmission in microwave frequency range in the past few years [5], [9], [27], [39]. For example, Irfan *et al* had successfully design an energy saving glass with dual bandpass FSS by hard coating technique [23]. From his findings, the FSS structure able to attenuates 92.7% IR radiation. While Syed *et al* had reported that combination of low pass and high pass FSS glass had 30dB transmission improvement in the microwave frequency range [6]. Besides that, Mats *et al* reported that the transmission improvement of 10dB had been achieved with FSS window [12]. Then, Rafique *et al* had successfully designed a dual band circular loop FSS with the improvement in transmission of 26.4dB [24]. Last but not least, Ghaffer *et al* had reported that cross dipole FSS had transmission improvement in the microwave frequency range of 11.3dB [27].



## REFERENCES

1. 2014. A Global Review. *Irrigation & Drainage in the World*. Retrieved Dec 14, 2014, from [http://www.icid.org/i\\_d\\_malaysia.pdf](http://www.icid.org/i_d_malaysia.pdf)
2. R. Heede. (2013). Tracing anthropogenic carbon dioxide and methane emissions to fossil fuel and cement producers, 1854–2010. *Clim. Change*, 122(1-2), pp. 229–241.
3. S. H. Sohail, G. I. Kiani, and K. P. Esselle. (2011). Parametric Analysis of RF and Microwave Transmission through Single and Multiple Layer of Float Glass. *Proceeding Asia-Pacific Microw. Convergence*, 2, pp. 1454–1457.
4. A. Z. Khan. (1966). Electrical energy conservation and its application to a sheet glass industry. *IEEE Trans. energy Convers.*, 11(3), pp. 666–671.
5. G. I. Kiani, L. G. Olsson, A. Karlsson, and K. P. Esselle. (2010) Transmission of infrared and visible wavelengths through energy-saving glass due to etching of frequency-selective surfaces. *IET Microwaves, Antennas Propag.*, 4(7), pp. 955-961.
6. G. I. Kiani, A. R. Weily and K. P. Esselle. (2006). A novel absorb/transmit FSS for secure indoor wireless networks with reduced multipath fading. *IEEE Microwave Wireless Components Letter*, 16(6), pp. 378–380.
7. Q. H. Li, A. H. Meng and Y. G. Zhang. (2009). Recovery Status and Prospect of Low-grade Waste Energy in China. *Sustainable Power Generation and Supply*, pp. 1–6.

8. S. I. Sohail, K. P. Esselle and G. Kiani. (2012). Design of a Bandpass FSS on Dual Layer Energy Saving Glass for Improved RF Communication in Modern Buildings. *Antennas and Propagation Society International Symposium*, pp. 1–2.
9. I. Ullah, D. Habibi and G. Kiani. (2011). Design of RF/Microwave efficient buildings using frequency selective surface. *2011 IEEE 22nd Int. Symp. Pers. Indoor Mobile Radio Communication*, pp. 2070–2074.
10. N. Yamauchi, T. Itoh and T. Noguchi. (2012). Low energy-cost TFT technologies using ultra thin flexible glass substrate. *19th International Workshop on Active-Matrix Flatpanel Displays and Devices*, pp. 213–214.
11. C. Yang, D. Yuan, and Y. Jia. (2012). Research on energy of an office building equipped high permeability with Low-E window in Xinxiang. *2012 2nd International Conference Consumer Electronics Communication Networks*, pp. 508–511.
12. M. Gustafsson, A. Karlsson, A. P. P. Rebelo, and B. Widenberg. (2006). Design of Frequency Selective Windows for Improved Indoor Outdoor Communication. *IEEE Transaction Antennas Propagation*, 54(6), pp. 1897–1900.
13. R. R. Kasar, N. G. Deshpande, Y. G. Gudage, J. C. Vyas, and R. Sharma. (2008). Studies and correlation among the structural, optical and electrical parameters of spray-deposited tin oxide (SnO<sub>2</sub>) thin films with different substrate temperatures. *Physics B Condensation Matter*, 403(19-20), pp. 3724–3729.
14. G. Korotcenkov and B. K. Cho. (2009). Thin film SnO<sub>2</sub>-based gas sensors: Film thickness influence. *Sensors Actuators B Chemistry*, 42(1), pp. 321–330.
15. E. Comini, G. Faglia, and G. Sberveglieri. (2001). UV light activation of tin oxide thin Films for NO<sub>2</sub> sensing at low temperatures. *Sensors and Actuators B: Chemical*, 78(1-3), pp. 73–77.

16. V. V Kissine, S. A. Voroshilov, and V. V Sysoev. (1999). Oxygen flow effect on gas sensitivity properties of tin oxide film prepared by r.f. sputtering. *Sensors Actuators B: Chemical*, 55(1), pp. 55–59.
17. R. Dolbec, M. a. El Khakani, a. M. Serventi, and R. G. Saint-Jacques. (2003). Influence of the nanostructural characteristics on the gas sensing properties of pulsed laser deposited tin oxide thin films. *Sensors Actuators B: Chemical*, 93(1-3), pp. 566–571.
18. S. Lee, J. Lee, T. Oh, and Y. Kim. (2003). Fabrication of tin oxide film by sol – gel method for photovoltaic solar cell system. *Solar Energy Materials and Solar Cells*, 75(3-4), pp. 481–487.
19. D. M. Mukhamedshina and N. B. Beisenkhanov. (2006). Chapter 9: Influence of Crystallization on the Properties of SnO<sub>2</sub> Thin Films. *Advances in Crystallization Processes Dr. Yitzhak Mastai (Ed.)*.
20. S. Sen and V. B. Patil. (2013). Nanocrystalline SnO<sub>2</sub> thin films : Structural , morphological , electrical transport and optical studies. *Journal of Alloys and Compounds*, 563, pp. 300–306.
21. M. Philippakis, C. Martel, D. Kemp, S. Appleton, and R. Pearson. (2004). Application of FSS Structures to Selectively Control the Propagation of signals into and out of buildings. *Antenna Systems(Era Technology)*, pp. 1–54.
22. P. T. Teo, X. F. Luo, and C. K. Lee. (2007). Frequency-selective surfaces for GPS and DCS1800 mobile communication , Part 1 : Quad-layer and single-layer FSS design. *IET Microwaves Antennas Propagation*, 1(2), pp. 314–321.
23. I. Ullah, X. Zhao, and G. K. Habibi, Daryoush. (2011). Transmission improvement of UMTS and Wi-Fi signals through energy saving glass using FSS. *Wireless and Microwave Technology Conference*, pp. 1-5.

24. U. Rafique, M. M. Ahmed, S. Member, M. A. Haq, and M. T. Rana. (2011). Transmission of RF Signals through Energy Efficient Window Using FSS. 7th Conference On *Emerging Technologies (ICET)*, pp. 1–4.
25. G. Kiani, L. Olsson, A. Karlsson, and K. Esselle. (2008). Transmission analysis of energy saving glass windows for the purpose of providing FSS solutions at microwave frequencies. *Antennas and Propagation Society International Symposium*, pp. 25–28.
26. J. Tan, Y. Liu. (2013). Frequency dependent model of sheet resistance and effect analysis on shielding effectiveness of transparent conductive mesh coatings. *Progress Electromagnetic Research*, 140, pp. 353–368.
27. G. I. Kiani, L. G. Olsson, A. Karlsson, K. P. Esselle, S. Member, and M. Nilsson. (2011). Cross-Dipole Bandpass Frequency Selective Surface for Energy-Saving Glass Used in Buildings. *IEEE Transactions on Antennas and Propagation*, 59(2), pp. 520–525.
28. Energy Saving Glass - Warm Coatings. *Pilkington*, Retrieved May 14, 2014, from <http://www.pilkington.com/coatings.htm>
29. C. Tsokonas. (2001). Optically transparent frequency selective window for microwave applications. *Electronics Letters IET*, 37(24), pp. 20–22.
30. B. Widenberg, J. Víctor, and R. Rodríguez. (2002). Design of Energy Saving Windows with High Transmission at 900 MHz and 1800 MHz. *CODEN: LUTEDX(TEAT-7110)*, pp. 1-14.
31. N. B. Huat and Z. Abidin (2011). An Overview of Malaysia Green Technology Corporation Office Building: A Showcase Energy-Efficient Building Project in Malaysia. *J. Sustain. Dev.*, 4(5), pp. 212–228.
32. M. Batzill and U. Diebold. (2005). The surface and materials science of tin oxide. *Prog. Surf. Sci.*, 79(2-4), pp. 47–154.

33. C. Mias, C. Tsakonas, C. Oswald, and B. Street. (2011). Department of Electrical and Electronic Engineering An Investigation into the Feasibility of designing Frequency Selective Windows employing periodic structures ( Ref . AY3922 ) Final Report for The Radiocommunications Agency. *The NottinghamTrent University,Electrical and Electronics Department, 44*, pp. 1-167.
34. M. Maleki and S. M. Rozati. (2013). An economic CVD technique for pure SnO<sub>2</sub> thin films deposition: Temperature effects. *Bull. Mater. Sci.*, 36(2), pp. 217–221.
35. M. Alaf, M. O. Guler, D. Gultekin, M. Uysal, A. Alp, and H. Akbulut. (2008). Effect of oxygen partial pressure on the microstructural and physical properties on nanocrystalline tin oxide films grown by plasma oxidation after thermal deposition from pure Sn targets. *Vacuum*, 83(2), pp. 292–301.
36. A. Faheem, M. Mehmood, A. M. Rana, and M. T. Bhatti. (2009). Applied Surface Science Effect of annealing on electrical resistivity of rf-magnetron sputtered nanostructured SnO<sub>2</sub> thin films. *Chinese Physics Letters*, 26(7), pp. 8562–8565.
37. Z. W. Chen, G. Liu, H. J. Zhang, G. J. Ding, Z. Jiao, M. H. Wu, C. H. Shek, C. M. L. Wu, and J. K. L. Lai. (2009). Insights into effects of annealing on microstructure from SnO<sub>2</sub> thin films prepared by pulsed delivery. *J. Non. Cryst. Solids*, 355(52-54), pp. 2647–2652.
38. B. F. Yu, Z. B. Hu, M. Liu, H. L. Yang, Q. X. Kong, and Y. H. Liu. (2009). Review of research on air-conditioning systems and indoor air quality control for human health. *Int. J. Refrig.*, 32(1), pp. 3–20.
39. C. Chen, S. Chen, W. Chuang, and J. Shieh. (2011). Transparent Glass Window with Energy-saving and Heat Insulation Capabilities. *Advances Materials Reseach*, 316, pp. 10–16.

40. I. Russo, L. Boccia, G. Amendola, G. Di Massa, and V. P. Bucci. (2010). Tunable Pass-Band FSS for Beam Steering Applications. *Proceeding of the Fourth European Conference on Antennas and Propagation*, pp. 1-4.
41. L. Ragan, A. Hassibi, T. S. Rappaport, and C. L. Christianson. (2007). Novel On-Chip Antenna Structures and Frequency Selective Surface (FSS) Approaches for Millimeter Wave Devices. *2007 IEEE 66th Veh. Technol. Conf.*, pp. 2051–2055.
42. G. Wu, V. Hansen, E. Kreysa, and H.-P. Gemuend. (2006). Design and Optimization of FSS Structures for Applications in (Sub) millimetre Astronomy Using a PSO Algorithm. *2006 Jt. 31st Int. Conf. Infrared Millim. Waves 14th Int. Conf. Teraherz Electron.*, (2), pp. 401.
43. L. Y. Seng, M. F. Abd Malek, W. F. Hoon, L. W. Leong, N. Saudin, L. Mohamed, N. A. Mohd Affendi, and A. B. Ali, “Frequency selective surface for enhance WLAN applications,” *2012 IEEE Symp. Wirel. Technol. Appl.*, vol. 2, no. 12, pp. 81–84, Sep. 2012.
44. I. H. Kim, J. H. Ko, D. Kim, K. S. Lee, T. S. Lee, J. -h. Jeong, B. Cheong, Y.-J. Baik, and W. M. Kim. (2006). Scattering mechanism of transparent conducting tin oxide films prepared by magnetron sputtering. *Thin Solid Films*, 515(4), pp. 2475–2480.
45. T. S. M. Tadatsugu, N. Hidehito. (1988). Highly Conducting and Transparent SnO<sub>2</sub> Thin Films Prepared by RF Magnetron Sputtering on Low-Temperature Substrates. *Japanese J. Appl. Physics*, 27(3), pp. 287–289.
46. D. Leng, L. Wu, H. Jiang, Y. Zhao, J. Zhang, W. Li, and L. Feng. (2012). Preparation and Properties of SnO<sub>2</sub> Film Deposited by Magnetron Sputtering. *Int. J. Photoenergy*, 2012, pp. 1–6.
47. L. P. Chikhale, J. Y. Patil, a. V. Rajgure, F. I. Shaikh, I. S. Mulla, and S. S. Suryavanshi. (2014). Structural, morphological and gas sensing properties of

- undoped and Lanthanum doped nanocrystalline SnO<sub>2</sub>. *Ceram. Int.*, 40(1), pp. 2179–2186.
48. L. Sangaletti, L. E. Depero, A. Dieguez, G. Marca, and J. R. Morante. (1997). Microstructure and morphology of tin dioxide multilayer thin film gas sensors. *Sensors and Actuators B*, 44 , pp. 268–274.
  49. B. S. Tosun, R. K. Feist, A. Gunawan, K. A. Mkhoyan, S. a. Campbell, and E. S. Aydil. (2012). Sputter deposition of semicrystalline tin dioxide films. *Thin Solid Films*, 520(7), pp. 2554–2561.
  50. B. Thangaraju, “Structural and electrical studies on highly conducting spray deposited fluorine and antimony doped SnO<sub>2</sub> thin films from SnCl<sub>2</sub> precursor. (2002). *Thin Solid Films*, 402(1-2), pp. 71–78.
  51. M. Z. A. A. Aziz, M. M. Shukor, M. K. Suaidi, B. H. Ahmad, M. F. Johar, S. N. Salleh, F. A. Azmin, and M. F. A. Malek. (2013). Impedance of the unit cell of the frequency selective surface at 2.4 GHz. *2013 3rd Int. Conf. Instrumentation, Commun. Inf. Technol. Biomed. Eng.*, 5(5), pp. 49–53.
  52. M. Z. A. A. Aziz, M. M. Shukor, B. H. Ahmad, M. K. Suaidi, M. F. Johar, M. A. Othman, S. N. Salleh, F. a. Azmin, and M. F. A. Malek. (2013). Investigation of a square loop Frequency Selective Surface (FSS) on hybrid material at 2.4 GHz. *2013 IEEE Int. Conf. Control Syst. Comput. Eng.*, pp. 275–278.
  53. 2006. Periodic Arrays: FSS and PBG. *CST Studio Suite 2006B Application Note*. Retrieved Dec 14, 2014, from <http://www.cst.com>.
  54. R. A. Pearson, B. Phillips, K. G. Mitchell, and M. Patel. (1996). Application of Waveguide Simulators to FSS and Wideband Radome Design. *IEE Colloquium On Advances In Electromagnetic Screens*, pp. 7/1-7/6.



55. M. R. Chaharmir, J. Shaker, and H. Legay. (2008). FSS-backed reflectarray with broadband square loop cell elements for dual-band application. *Antennas and Propagation Society International Symposium*, pp. 1–4.
56. M. Hajj, E. Rodes, and T. Monédière. (2009). Dual-Band EBG Sectoral Antenna Using a Single-Layer FSS for UMTS Application, *IEEE Antennas and Wireless Propagation Letters*, 8, pp. 161–164.
57. A. Munir, V. Fusco, U. Kingdom, and H. D. Technique. (2008). A Hybrid De-embedding Technique and Its Application for FSS Characterization. *Asia Pacific Microwave Conference*, pp. 1-4.
58. R. U. Nair, A. Neelam, and R. M. Jha. (2009). A novel Jerusalem cross FSS embedded A-sandwich radome for aerospace applications. *2009 Appl. Electromagn. Conf.*, pp. 1–4.
59. B. Wang, Q. Wang, A. Liao, L. Chen, and W. Mai. (2009). Design of a FSS filter with shorting stubs for compact E-plane duplexer application. *2009 3rd IEEE Int. Symp. Microwave, Antenna, Propag. EMC Technol. Wirel. Commun.*, pp. 1040–1042.
60. R. M. S. Cruz, A. G. D. Assunção, and P. H. F. Silva. (2010). A New FSS Design Proposal for UWB Applications. *International Workshop On Antenna Tehnology* , pp. 1-4.
61. G. I. Kiani and T. S. Bird. (2011). FSS Modulator for Future High Speed Communication Applications. *Asia Pacific Microwave Conference*, pp. 845–848.
62. T. Zhang, H. H. Ouslimani, Y. Letestu, a. Le Bayon, and L. R. Darvil. (2012). A low profile multilayer seventh order band-pass frequency selective surface (FSS) for millimeter-wave application. *WAMICON 2012 IEEE Wirel. Microw. Technol. Conf.*, pp. 1–4.



63. H. Y. Chen and Y. K. Chou, "An EMI shielding FSS for Ku-band applications," *Proc. 2012 IEEE Int. Symp. Antennas Propag.*, pp. 1–2, Jul. 2012.
64. G. Kiani and V. Dyadyuk. (2012). Low loss FSS polarizer for 70 GHz applications. *Proc. 2012 IEEE Int. Symp. Antennas Propag.*, pp. 1–2.
65. M. Moallem and K. Sarabandi. (2012). A Spatial Image Rejection Filter Based on Element FSS for J-band Radar Applications. *Antennas and Propagation Society International Symposium*, pp. 1-2.
66. W. Xiao-di, L. V Xu-liang, Z. Zhao-yang, and P. Bai-cai. (2012). A Design of Multi-band Stealth Compatibility with the Application of Fusion Type FSS. *International Workshop on Metamaterials*, pp. 1-4.
67. B. G. Xia, C. F. Yao, J. Huang, J. Meng, D. H. Zhang, and J. S. Zhang. (2013). Terahertz FSS for space borne passive remote sensing application. *Electron. Lett.*, 49(22), pp. 1398–1399.
68. H. Liu, K. L. Ford, and R. J. Langley. (2008). Miniaturised bandpass frequency selective surface with lumped components. *IEEE Electronics Letters*, 44(18), pp. 1054-1055.
69. M. Yang, A. K. Brown, and S. Member. (2010). A Hybrid Model for Radio Wave Propagation Through Frequency Selective Structures ( FSS )," *IEEE Trans. Antennas Propag.*, 58(9), pp. 2961–2968.
70. M. Ying, T. Hori, M. Funmoto, T. Se, K. Sato, and I. Oshima. (2013). Unit Cell Structure of AMC with Multi-Layer Patch Type FSS for Miniaturization. *IEEE Trans. Antennas Propag.*, 2, pp. 957–960.
71. X. Meng and A. Chen. (2009). Influence of cross-loop slots FSS structure parameters on frequency response. *2009 3rd IEEE Int. Symp. Microwave, Antenna, Propag. EMC Technol. Wirel. Commun.*, pp. 939–942.

72. A. Edalati, S. Member, T. A. Denidni, and S. Member. (2011). High-Gain Reconfigurable Sectoral Antenna Using an Active Cylindrical FSS Structure. *IEEE Trans. Antennas Propag.*, 59(7), pp. 2464–2472.
73. A. Qing and C. K. Lee. (2001). An Improved Model for Full Wave Analysis of Multilayered Frequency Selective Surface with Gridded Square Element. *Prog. Electromagn. Res.*, 30, pp. 285–303.
74. S. K. Tripathy, B. P. Hota, and P. V Rajeswari. (2013). Study of Optical Characteristics of Tin oxide thin film prepared by Sol-Gel Method. *Bull. Master Sci.*, 36(7), pp. 1231-1237.
75. Z. Jin, H.-J. Zhou, Z.-L. Jin, R. F. Savinell, and C.-C. Liu. (1998). Application of nano-crystalline porous tin oxide thin film for CO sensing. *Sensors Actuators B Chem.*, 52(1-2), pp. 188–194.
76. V. Baranauskas, M. Fontana, Z. J. Guo, H. J. Ceragioli, and A. C. Peterlevitz. (2005). Field-emission properties of nanocrystalline tin oxide films. *Sensors Actuators B Chem.*, 107(1), pp. 474–478.
77. H. N. Lee, B. J. Song, and J. C. Park. (2014). Fabrication of p-Channel Amorphous Tin Oxide Thin-Film Transistors Using a Thermal Evaporation Process. *J. Disp. Technol.*, 10(4), pp. 288–292.
78. C. Lin, D. Zhang, and X. Liu. (2012). A study of tin oxide thin film gas sensors with high oxygen vacancies. *2012 7th IEEE Int. Conf. Nano/Micro Eng. Mol. Syst.*, pp. 693–697.
79. P. J. Kelly and R. D. Arnell. (2000). Magnetron sputtering : a review of recent developments and applications,” 56, pp. 159–172.
80. S. Baco, A. Chik, and F. Yassin. (2012). Study on Optical Properties of Tin Oxide Thin Film at Different Annealing Temperature. *Journal of Science and Technology*, 4(1), pp. 61-72.

81. G. Xiaoyong, F. Hong-Liang, Z. Zeng-Yuan, M. Jiao-Min, Z. Meng-Ke, C. Chao, G. Jin-Hua, Y. Shi-E, C. Yong-Sheng, and L. Jing-Xiao. (2011). Effect of the Oxygen Flux Ratio on the Structural and the Optical Properties of Silver-oxide Films Deposited by Using the Direct-current Reactive Magnetron Sputtering Method. *J. Korean Phys. Soc.*, 58(2), pp. 243.
82. N. Bin Nayan. (2008). Studies on high – pressure magnetron sputtering plasmas using laser – aided diagnostic techniques. *Nagoya University*.
83. A. S. Reddy, N. M. Figueiredo, and A. Cavaleiro. (2012). Pulsed direct current magnetron sputtered nanocrystalline tin oxide films. *Applied Surface Science*, 258(22), pp. 8902–8907.
84. G-J. Janssen. Information on the FESEM (Field-emission Scanning Electron Microscope), *Radboud Universiteit Nijmegen*, pp. 1-5. Retrieved May 14, 2014, from [www.sem.com/analytic/sem.htm](http://www.sem.com/analytic/sem.htm).
85. (1986). Non-Contact Mode AFM in Ambient Atmosphere. pp. 85–88. Retrieved May 14, 2014, from [www.parkAFM.com](http://www.parkAFM.com).
86. (2004). Introduction to Grazing Incidence Diffraction. *Bruker AFS*, pp. 1–29. Retrieved May 14, 2014, from <http://mmlab.dlut.edu.cn/training/gid>.
87. S. Conference. (1998). A simple formula for calculating the frequency-dependent resistance of a round wire. *Microwave and Optical Technology Letters*, 19(2), pp. 84–85.
88. G. I. Kiani, A. Karlsson, and L. Olsson. (2007). Glass Characterization for Designing Frequency Selective Surfaces to Improve Transmission through Energy Saving Glass Windows. *Asia Pacific Microwave Conference*, pp. 1-4.
89. M. Kolif. (2001). Relationships among Properties of Sputtered Thin Films and Sputtering Process Parameters. *International Spring Seminar On Electronic Packaging*, pp. 42–46.

90. G. Korotcenkov, V. Brinzari, J. Schwank, M. Dibattista, and A. Vasiliev. (2001). Peculiarities of SnO<sub>2</sub> thin films deposition by spray pyrolysis for gas sensor application. *Sensors and Actuators*, 77(2001), pp. 244–252.
91. M. Keum and J. Han. (2008). Preparation of ITO Thin Film by Using DC Magnetron Sputtering. *Journal of Korean Physical Society*, 53(3), pp. 1580–1583.

